Memory Microcircuit - Page 1 of 1



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275.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
C-2a aircraft (reprocured), b-1 aircraft support equipment. C-17a airlifter aircraft. Mh-53 e helicopter. Sh-60f asw carrier based helicopter
Austin ship class lpd-4 amphibious transport docks.
Features Provided:
Monolithic and ultraviolet erasable and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
25.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.0 volts total supply
Memory Device Type:
Eprom
Special Features:
Weapon system essential
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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